UNISONIC TECHNOLOGIES CO., LTD

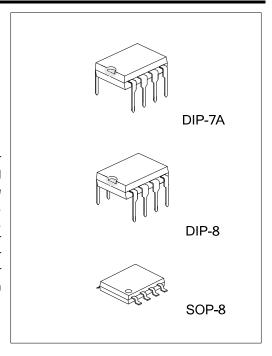
US1652

LINEAR INTEGRATED CIRCUIT

HIGH PERFORMANCE CURRENT MODE POWER **SWITCH**

DESCRIPTION

The UTC US1652 is an integrated PWM controller and Power MOSFET specifically designed for switching operation with minimal external components. The UTC US1652 is designed to provide several special enhancements to satisfy the needs, for example, Power-Saving mode for low standby power, Frequency Hopping, Constant Output Power Limiting , Slope Compensation ,Over Current Protection (OCP), Over Voltage Protection (OVP), Over Load Protection (OLP), Under Voltage Lock Out (UVLO), Over Temperature Protection (OTP), etc. IC will be shutdown or can auto-restart in situations.

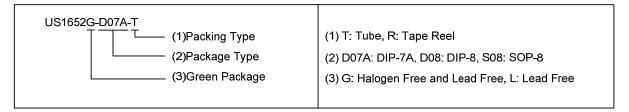


FEATURE

- * Internal Power MOSFET (650V)
- * Programming Gate Driver Capability
- * Frequency hopping for Improved EMI Performance.
- * Lower than 100mW Standby Power Design
- * Linearly decreasing frequency to 20~35KHz during light load
- * Internal Soft start
- * Internal Slope Compensation
- * Constant Power Limiting for universal AC input Range
- * Gate Output Maximum Voltage Clamp(16V)
- * Over temperature protection
- * Over load protection
- * Over voltage protection
- * Leading edge blanking
- * Cycle-by-Cycle current limiting
- * Under Voltage Lock Out

ORDERING INFORMATION

Ordering Number		Dooleage	Dooking	
Lead Free	Halogen Free	Package	Packing	
US1652L-D07A-T	US1652G-D07A-T	DIP-7A	Tube	
US1652L-D08-T	US1652G-D08-T	DIP-8	Tube	
US1652L-S08-R	US1652G-S08-R	SOP-8	Tape Reel	

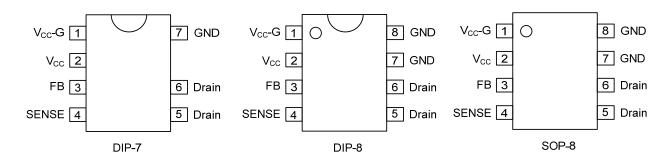


www.unisonic.com.tw 1 of 10

■ MARKING

PACKAGE	MARKING			
DIP-7A	7 6 5 UTC DDD L: Lead Free UC1652 DG: Halogen Free 1 2 3 4			
DIP-8	Date Code UTC US1652 US1652 L: Lead Free G: Halogen Free Lot Code			
SOP-8	Date Code UTCOOO US1652			

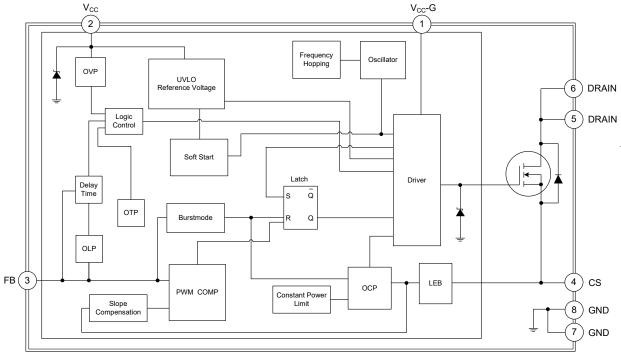
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.		DININIANAE	DECORIDATION		
DIP-7A	DIP-8/SOP-8	PIN NAME	DESCRIPTION		
1	1	Vcc-G	Supply voltage		
2	2	Vcc	Supply voltage		
3	3	FB	Feedback		
4	4	SENSE	Current sense input		
5	5	DRAIN	Power MOSFET drain		
6	6	DRAIN	Power MOSFET drain		
_	7	GND	Ground		
7	8	GND	Ground		

■ BLOCK DIAGRAM



Notes: OLP (Over Load Protection)

OVP (Over Voltage Protection)

OTP (Over Temperature Protection)

OCP (Over Current Protection)

UVLO (Under Voltage Latch-Out)

LEB (Led Edge Blanking)

■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	Vcc	33	V
Input Voltage to FB Pin	V_{FB}	-0.3 ~ 6.5	V
Input Voltage to CS Pin	Vcs	-0.3 ~ 6.5	V
Junction Temperature	TJ	+150	°C
Operating Temperature	Topr	-40 ~ +125	°C
Storage Temperature	T _{STG}	-50 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ OPERATING RANGE

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	Vcc	10 ~ 24	V
V _{CC} -G Pin Series Resistor	V _{CC_GR}	51 ~ 1000	Ω
Open Frame Output Power for 85~264VAC	Po MAX	12	W

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, V_{CC}=15V, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY SECTION						
Start Up Current	Ist	$V_{CC} = V_{THD(ON)}-1V$		2	15	μA
Supply Current with Switch	lop	V _{FB} = 3.5V		3	5.5	mA
V _{DD} Zener Clamp Voltage	VCLAMP	I _{VDD} =20mA	29	31	33	V
UNDER-VOLTAGE LOCKOUT SECTION		<u> </u>				
Start Threshold Voltage	V _{THD(ON)}		18	20	22	V
Min. Operating Voltage	Vcc(MIN)		6.5	8	9.5	V
CONTROL SECTION				•		
Feedback Source Current	I _{FB}	V _{FB} =0		240		uA
V _{FB} Open Loop Voltage Level	V _{FB} _Open			5.4		V
Burst-Mode Out FB Voltage	V _{FB(OUT)}	V _{CS} =0		1.42		V
Burst-Mode Enter FB Voltage	V _{FB(IN)}	V _{CS} =0		1.35		V
Switching Normal Initial	F _(SW)	$V_{FB} = 3.5V$	60	65	70	kHz
Frequency Burst mode base frequecy	T (SW)		20			kHz
Duty Cycle	DMAX	V _{FB} =3.5V, V _{CS} =0	70	80	90	%
Frequency Hopping	F _{J(SW)}		-9		+9	%
Frequency Variation VS Vcc Deviation	F _{DV}	V _{CC} =10 ~ 20V			10	%
Frequency Variation VS Temperature Deviation	n F _{DT}	T=-40 ~ 110°C			10	%
Soft-Start Time	Tsofts			5		ms
PROTECTION SECTION	1		T	1		
OVP Threshold	Vovp	V _{FB} =3.5V	25	26	27	V
OLP Threshold	V _{FB(OLP)}	Vcs=0		4.4		V
Delay Time Of OLP	T _{D-OLP}		60	88	120	ms
OTP Threshold	T _(THR)			140		°C
CURRENT LIMITING SECTION				1	1	
Leading Edge Blanking Time	t _{LEB}		200	450	700	nS
Peak Current Limitation	V _{SENSE-H}	V _{FB} =3.9V		0.92		V
Threshold Voltage For Valley	Vsense-l	V _{FB} =3.9V	0.73	0.79	0.85	V
POWER MOS-TRANSISTOR SECTION				1		
Drain-Source Breakdown Voltage	V _{DSS}	V_{GS} =0V, I_D =250 μ A	650			V
Turn-on voltage between gate and source	V _{TH}	V _{DS} =V _{GS} , I _D =250µA	2		4	V
Drain-Source Diode Continuous Source Currer	nt Is				2	Α
Static Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =10 V , I_D =0.8 A		5.5	6.5	Ω

■ FUNCTIONAL DESCRIPTION

The internal reference voltages and bias circuit work at V_{CC}> V_{THD(ON)}, and shutdown at V_{CC}<V_{CC(MIN)}.

(1) Soft-Start

When every IC power on, driver output duty cycle will be decided by inter-slope voltage V_{SOFTS} and V_{CS} on current sense resistor at beginning. After the whole soft-start phase end, and driver duty cycle depend on V_{FB} and V_{CS} . The relation among V_{SOFTS} , V_{FB} and V_{OUT} as followed Fig.3. Furthermore, soft-start phase should end before V_{CC} reach $V_{CC(MIN)}$ during V_{CC} power on. Otherwise, if soft-start phase remain not end before V_{CC} reach $V_{CC(MIN)}$ during V_{CC} power on, IC will enter auto-restart phase and not set up V_{OUT} .

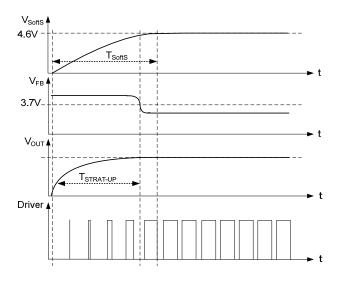


Fig.3 Soft-start phase

(2) Switching Frequency Set

The maximum switching frequency is set to 65kHz. Switching frequency is modulated by output power Pout during IC operating. At no load or light load condition, most of the power dissipation in a switching mode power supply is from switching loss on the MOSFET transistor, the core loss of the transformer and the loss on the snubber circuit. The magnitude of power loss is in proportion to the number of switching events within a fixed period of time. So lower Switching frequency at lower load, which more and more improve IC's efficiency at light load. At from no load to light load condition, The IC will operate at from Burst mode to Reducing Frequency Mode. The relation curve between fsw and Pout/Pout(MAX) as followed Fig.4.

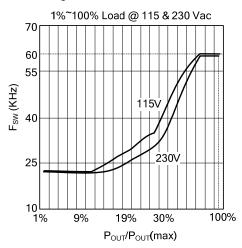


Fig.4 The relation curve between fsw and relative output power Pout/ Pout (MAX)

■ FUNCTIONAL DESCRIPTION (Cont.)

(3) Internal Synchronized Slope Compensation

Built-in slope compensation circuit adds voltage ramp onto the current sense input voltage for PWM generation, this greatly improves the close loop stability at CCM and prevents the sub-harmonic oscillation and thus reduces the output ripple voltage.

(4) Frequency Hopping For EMI Improvement

The Frequency Hopping is implemented in the IC; there are two oscillators built-in the IC. The first oscillator is to set the normal switching frequency; the switching frequency is modulated with a period signal generated by the 2nd oscillator. The relation between the first oscillator and the 2nd oscillator as followed Fig.5. So the tone energy is evenly spread out, the spread spectrum minimizes the conduction band EMI and therefore eases the system design in meeting stringent EMI requirement.

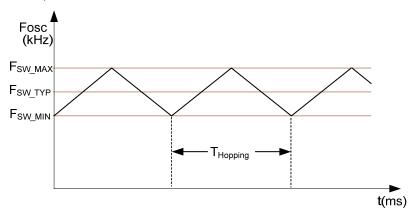


Fig.5 Frequency Hopping

(5) Constant Output Power Limit

When the primary current, across the primary wind of transformer, reaches the limit current, the output GATE driver will be turned off after a small propagation delay t_D. This propagation delay will introduce an additional current proportional to t_D×V_{IN}/Lp. Since the propagation delay is nearly constant regardless of the input line voltage V_{IN}. Higher input line voltage will result in a larger additional current and hence the output power limit is also higher than that under low input line voltage. To compensate for this output power limit variation across a wide AC input range, the threshold voltage is adjusted by adding a positive ramp. This ramp signal rises from V_{SENSE-L} to V_{SENSE_H}, and then flattens out at V_{SENSE_H}. A smaller threshold voltage forces the output GATE drive to terminate earlier. This reduces the total PWM turn-on time and makes the output power equal to that of low line input. This proprietary internal compensation ensures a constant output power limit for a wide AC input voltage range (90VAC to 264VAC).

(6) Protection section

The IC takes on more protection functions such as OLP, OVP and OTP etc. In case of those failure modes for continual blanking time, the driver is shut down. At the same time, IC enters auto-restart, Vcc power on and driver is reset after Vcc power on again.

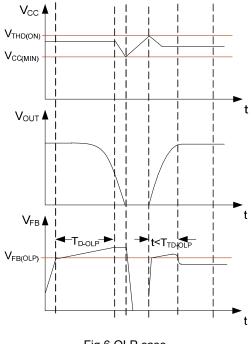
OLP

After power on, IC will shutdown driver if over load state occurs for continual T_{D-OLP}. OLP case as followed Fig.6.

OVP

OVP will shutdown the switching of the power MOSFET whenever $V_{\text{CC}} > V_{\text{OVP}}$. The OVP case as followed Fig.7.

■ FUNCTIONAL DESCRIPTION (Cont.)



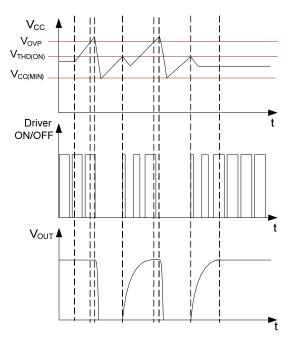


Fig.6 OLP case

Fig.7 OVP case

OTP

OTP will shut down driver when junction temperature T_J>T_(THR) for continual a blanking time.

(7) Driver Output Section

The driver-stage drives the gate of the MOSFET and is optimized to minimize EMI and to provide high circuit efficiency. This is done by reducing the switch on slope when reaching the MOSFET threshold. This is achieved by a slope control of the rising edge at the driver's output. The output driver is clamped by an internal 16V Zener diode in order to protect power MOSFET transistors against undesirable gate over voltage.

In addition to the gate drive control scheme mentioned, the gate drive strength can also be adjusted externally by a resistor connected between V_{DD} and V_{DD} -G, the falling edge of the Drain output can be well controlled. It provides great flexibility for system EMI design.

(8) Inside power switch MOS transistor

Specific power MOS transistor parameter is as "POWER MOS TRANSISTOR SECTION" in electrical characteristics table.

■ TYPICAL APPLICATION CIRCUIT

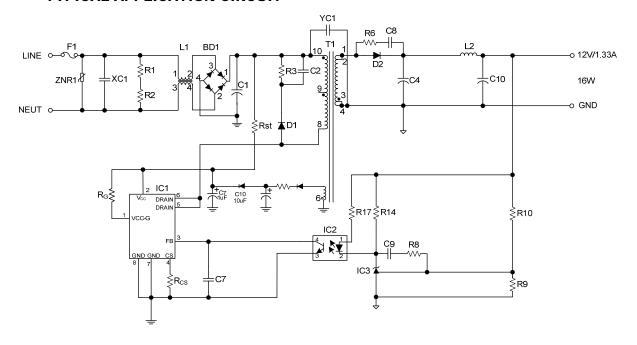
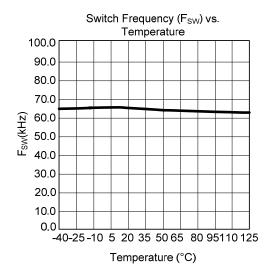
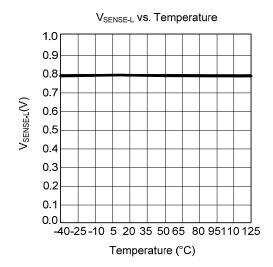
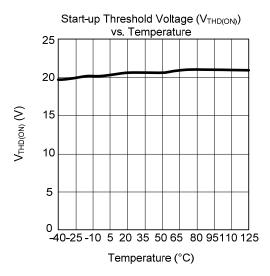


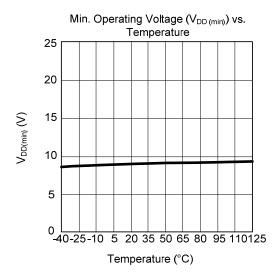
Fig.8 UTC US1602 Typical Application Circuit

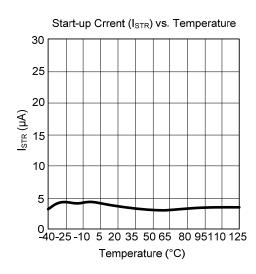
■ TYPICAL CHARACTERISTICS

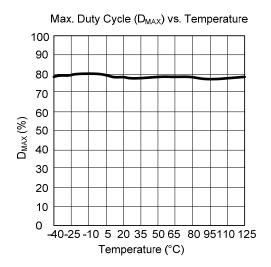












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